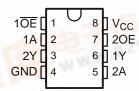
SCES535A-DECEMBER 2003-REVISED MARCH 2005

FEATURES

- Available in the Texas Instruments
 NanoStar™ and NanoFree™ Packages
- Optimized for 1.8-V Operation and Is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I_{off} Supports Partial-Power-Down Mode Operation
- Sub-1-V Operable
- Max t_{pd} of 1.9 ns at 1.8 V
- Low Power Consumption, 10 μA at 1.8 V
- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DCT OR DCU PACKAGE (TOP VIEW)



YEP OR YZP PACKAGE (BOTTOM VIEW)

GND	0 4	50	2A
GND 2Y	○ 3	60	1Y
1A	02	70	20E
1A 1OE	01	80	Vcc
			,

DESCRIPTION/ORDERING INFORMATION

This dual buffer/driver is operational at 0.8-V to 2.7-V V_{CC}, but is designed specifically for 1.65-V to 1.95-V V_{CC} operation.

The SN74AUC2G241 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The device is organized as two 1-bit line drivers with separate output-enable (1OE, 2OE) inputs. When 1OE is low or 2OE is high, the device passes data from the A inputs to the Y outputs. When 1OE is high or 2OE is low, the outputs are in the high-impedance state.

NanoStar™ and NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

ORDERING INFORMATION

TA	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING (2)
- MB	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YEP	Tape and reel	SN74AUC2G241YEPR	
-40°C to 85°C	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Tape and reel	SN74AUC2G241YZPR	U2_
	SSOP - DCT	Tape and reel	SN74AUC2G241DCTR	U41
	VSSOP - DCU	Tape and reel	SN74AUC2G241DCUR	U2_

- (1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
- (2) DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site.

 DCU: The actual top-side marking has one additional character that designates the assembly/test site.

 YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, · = Pb-free).

PDPlease be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor, and OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sinking/current-sourcing capability of the driver.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

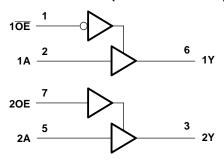
For more information about AUC Little Logic devices, please refer to the TI application report, *Applications of Texas Instruments AUC Sub-1-V Little Logic Devices*, literature number SCEA027.

FUNCTION TABLES

INP	JTS	OUTPUT
1 OE	1A	1Y
L	Н	Н
L	L	L
Н	X	Z

INP	JTS	OUTPUT
20E	2A	2Y
Н	Н	Н
Н	L	L
L	Х	Z

LOGIC DIAGRAM (POSITIVE LOGIC)





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Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range	Supply voltage range			
VI	Input voltage range (2)		-0.5	3.6	V
Vo	Voltage range applied to any output in the h	nigh-impedance or power-off state (2)	-0.5	3.6	V
Vo	Output voltage range ⁽²⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±20	mA
	Continuous current through V_{CC} or GND			±100	mA
		DCT package		220	
θ_{JA}	Package thermal impedance (3)	DCU package		227	°C/W
		YEP/YZP package		102	
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

³⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

SN74AUC2G241 **DUAL BUFFER/DRIVER WITH 3-STATE OUTPUTS**





Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		0.8	2.7	V
		V _{CC} = 0.8 V	V _{cc}		
V_{IH}	High-level input voltage	V _{CC} = 1.1 V to 1.95 V	0.65 × V _{CC}		V
		V _{CC} = 2.3 V to 2.7 V	1.7		
		V _{CC} = 0.8 V		0	
V_{IL}	Low-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V		0.7	
V _I	Input voltage		0	3.6	V
\/	Outrout welte re	Active state	0	V _{CC}	V
Vo	Output voltage	3-state	0	3.6	V
	High-level output current	$V_{CC} = 0.8 \text{ V}$		-0.7	
		V _{CC} = 1.1 V		الم	
I_{OH}		V _{CC} = 1.4 V		-5	mA
		V _{CC} = 1.65 V		-8	
		$V_{CC} = 2.3 \text{ V}$		-9	
		V _{CC} = 0.8 V		0.7	
		$V_{CC} = 1.1 V$	3 5		
I_{OL}	Low-level output current	$V_{CC} = 1.4 \text{ V}$			mA
		V _{CC} = 1.65 V		8	
		$V_{CC} = 2.3 \text{ V}$	9		
		$V_{CC} = 0.8 \text{ V to } 1.65 \text{ V}^{(2)}$		20	
$\Delta t/\Delta v$	Input transition rise or fall rate	V _{CC} = 1.65 V to 1.95 V ⁽³⁾		20	ns/V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}^{(3)}$		20	
T_A	Operating free-air temperature		-40	85	°C

 ⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.
 (2) The data was taken at C_L = 15 pF, R_L = 2 kΩ (see Figure 1).
 (3) The data was taken at C_L = 30 pF, R_L = 500 Ω (see Figure 1).





Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

Р	ARAMETER	TEST CONDITIO	NS	V _{cc}	MIN	TYP ⁽¹⁾	MAX	UNIT
		I _{OH} = -100 μA		0.8 V to 2.7 V	V _{CC} - 0.1			
		$I_{OH} = -0.7 \text{ mA}$		0.8 V		0.55		
.,		$I_{OH} = -3 \text{ mA}$		1.1 V	0.8			V
V _{OH}		$I_{OH} = -5 \text{ mA}$		1.4 V	1			V
		$I_{OH} = -8 \text{ mA}$		1.65 V	1.2			
		I _{OH} = -9 mA		2.3 V	1.8			
		I _{OL} = 100 μA		0.8 V to 2.7 V			0.2	
V-		$I_{OL} = 0.7 \text{ mA}$	0.8 V		0.25			
		I _{OL} = 3 mA		1.1 V			0.3	V
V _{OL}		I _{OL} = 5 mA		1.4 V			0.4	V
OL .		I _{OL} = 8 mA		1.65 V			0.45	
		I _{OL} = 9 mA		2.3 V			0.6	
I	All inputs	V _I = V _{CC} or GND		0 to 2.7 V			±5	μΑ
I _{off}		V_I or $V_O = 2.7 \text{ V}$		0			±10	μΑ
l _{OZ}		$V_O = V_{CC}$ or GND		2.7 V			±10	μΑ
I _{CC}		$V_I = V_{CC}$ or GND,	I _O = 0	0.8 V to 2.7 V			10	μΑ
C _i		V _I = V _{CC} or GND		2.5 V		2.5		pF
Co		$V_O = V_{CC}$ or GND		2.5 V		5.5		pF

⁽¹⁾ All typical values are at $T_A = 25$ °C.

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 0.8 V		V _{CC} = 1.2 V ± 0.1 V V _{CC} = 1.5 V ± 0.1 V				V _{CC} = 1.5 V ± 0.1 V		_C = 1.8 0.15 V		V _{CC} = ± 0.		UNIT
	(IIVFO1)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX			
t _{pd}	Α	Y	5.1	1	3.5	0.8	2.3	0.7	1.2	1.9	0.6	1.4	ns		
t _{en}	OE or OE	Υ	5.9	1.2	4.2	1	2.7	0.9	1.3	2	0.8	1.6	ns		
t _{dis}	OE or OE	Υ	6.2	2.2	4.8	2.5	4.4	1	2.9	4.2	1.6	3.3	ns		

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 1 ± 0.2	2.5 V 2 V	UNIT	
	(INFOT)	(001701)	MIN	TYP	MAX	MIN	MAX	
t _{pd}	A	Υ	0.9	1.6	2.5	0.8	1.8	ns
t _{en}	OE or OE	Υ	1.1	1.7	2.8	1	2	ns
t _{dis}	OE or OE	Υ	1.9	2.3	3.6	0.9	2.1	ns

SN74AUC2G241 DUAL BUFFER/DRIVER WITH 3-STATE OUTPUTS





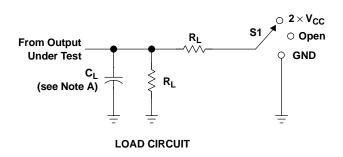
Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{CC} = 0.8 V TYP	V _{CC} = 1.2 V TYP	V _{CC} = 1.5 V TYP	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	UNIT
C_{pd}	Power dissipation capacitance	f = 10 MHz	16	16	16	17	18	pF

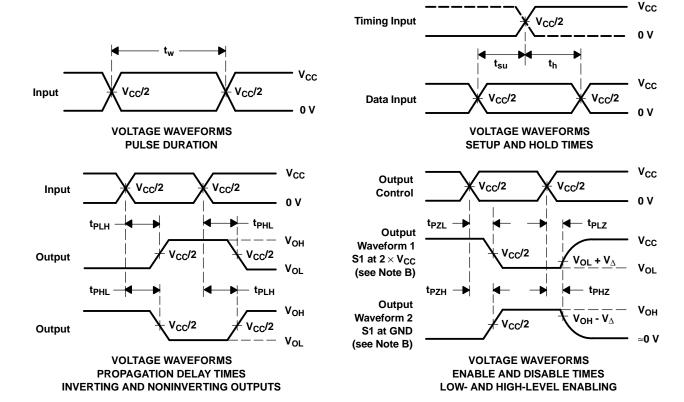


PARAMETER MEASUREMENT INFORMATION



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	2×V _{CC}
t _{PHZ} /t _{PZH}	GND

V _{CC}	CL	R _L	$\mathbf{V}_{\!\Delta}$
0.8 V	15 pF	2 k Ω	0.1 V
1.2 V \pm 0.1 V	15 pF	2 k Ω	0.1 V
1.5 V \pm 0.1 V	15 pF	2 k Ω	0.1 V
1.8 V \pm 0.15 V	15 pF	2 k Ω	0.15 V
2.5 V \pm 0.2 V	15 pF	2 k Ω	0.15 V
1.8 V \pm 0.15 V	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	30 pF	500 Ω	0.15 V
		1	1



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{Ω} = 50 Ω , slew rate \geq 1 V/ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd}.
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



PACKAGE OPTION ADDENDUM

6-Jun-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74AUC2G241DCURE4	ACTIVE	US8	DCU	8	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC2G241DCTR	ACTIVE	SM8	DCT	8	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC2G241DCUR	ACTIVE	US8	DCU	8	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC2G241YEPR	ACTIVE	WCSP	YEP	8	3000	TBD	SNPB	Level-1-260C-UNLIM
SN74AUC2G241YZPR	ACTIVE	WCSP	YZP	8	3000	Pb-Free (RoHS)	SNAGCU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

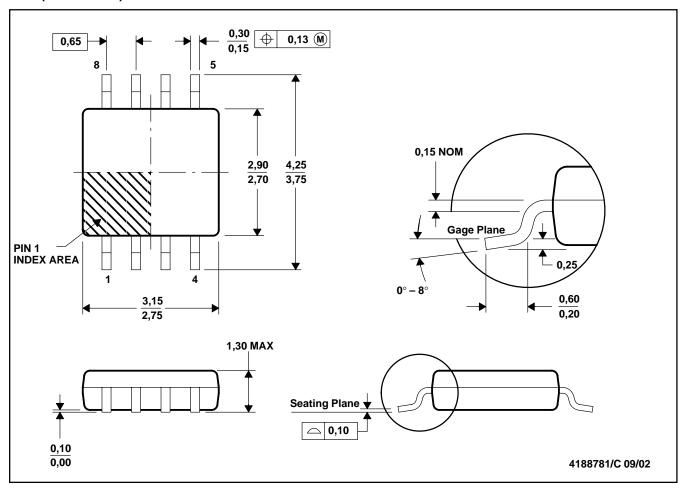
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

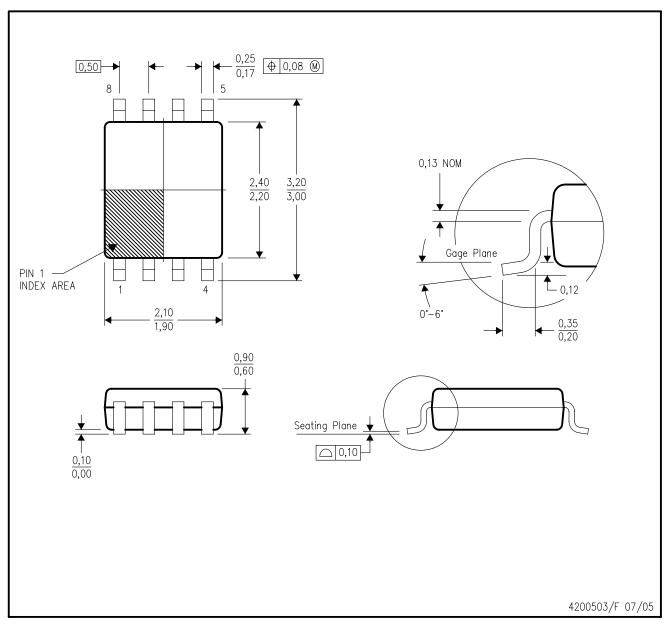


NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.C. Body dimensions do not include mold flash or protrusion
- D. Falls within JEDEC MO-187 variation DA.

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



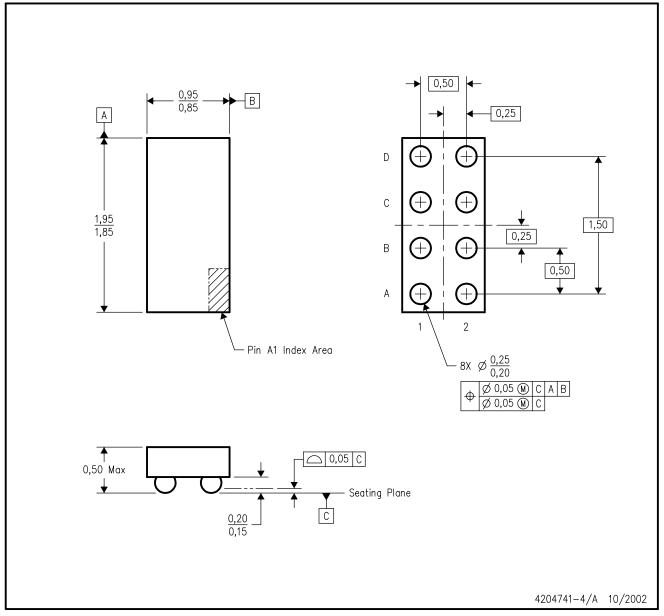
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-187 variation CA.



YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



NOTES:

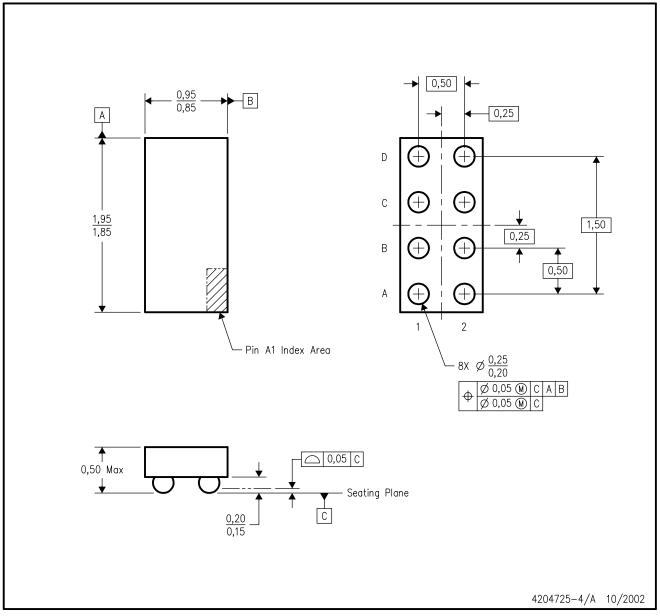
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is lead—free. Refer to the 8 YEP package (drawing 4204725) for tin—lead (SnPb).

NanoFree is a trademark of Texas Instruments.



YEP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. NanoStar™ package configuration.
- D. This package is tin-lead (SnPb). Refer to the 8 YZP package (drawing 4204741) for lead-free.

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